

Product Overview

NTH027N65S3F: Power MOSFET, N-Channel, SUPERFET® III, FRFET®, 650 V, 75 A, 27.4 mΩ , TO-247

For complete documentation, see the data sheet.

SUPERFET III MOSFET is ON Semiconductor's brand-new high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low on-resistance and lower gate charge performance. This advanced technology is tailored to minimize conduction loss, provide superior switching performance, and withstand extreme dv/dt rate.

Consequently, SUPERFET III MOSFET is very suitable for the various power systems for miniaturization and higher efficiency. SUPERFET III FRFET MOSFET's optimized reverse recovery performance of body diode can remove additional component and improve system reliability.

Features

- 700 V @ T_J = 150 °C
- Ultra Low Gate Charge (Typ. Q_g = 259 nC)
- Low Effective Output Capacitance (Typ. C_{oss}(eff.) = 1972 pF)
- Excellent body diode performance (low Q_{rr}, robust body diode)
- Optimized Capacitance
- RoHS Compliant
- 100% Avalanche Tested
- Typ. R_{DS(on)} = 23 mΩ

Applications

- Telecommunication
- Cloud system
- Industrial

Benefits

- Higher system reliability at low temperature operation
- Lower switching loss
- Lower switching loss
- Higher system reliability in LLC and Phase shift full bridge circuit
- Lower peak V_{ds} and lower V_{gs} oscillation

End Products

- Telecom power
- Server power
- EV charger
- Solar / UPS

Part Electrical Specifications

Product	Pricing (\$/Unit)	Compliance	Status	Channel Polarity	Configuration	V _{(BR)DSS} Min (V)	V _{GS} Max (V)	V _{GS(th)} Max (V)	I _D Max (A)	P _D Max (W)	R _{DS(on)} Max @ V _{GS} = 2.5 V (mΩ)	R _{DS(on)} Max @ V _{GS} = 4.5 V (mΩ)	R _{DS(on)} Max @ V _{GS} = 10 V (mΩ)	Q _g Typ @ V _{GS} = 4.5 V (nC)	Q _g Typ @ V _{GS} = 10 V (nC)	C _{iss} Typ (pF)	Package Type
NTH027N65S3F-F155	6.953	Pb-free	Active	N-Channel	Single	650	30	5	75	595	-	-	27.4	6	259	7690	TO-247-3

For more information please contact your local sales support at www.onsemi.com.

Created on: 3/29/2020